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# Electron-correlation molecular formations and spectra in three-electron hybrid double-well qubits

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We show that systematic full configuration-interaction (FCI) calculations enable prediction of the energy spectra and the intrinsic spatial and spin structures of the many-body wave functions as a function of the detuning parameter for the case of three-electron hybrid qubits based on GaAs asymmetric double quantum dots. Specifically, in comparison with the case of weak interactions and treating the entire three-electron double-dot hybrid qubit as an integral unit, it is shown that the predicted spectroscopic patterns, originating from strong electron correlations, manifest the formation of Wigner molecules (WMs). Signatures of WM formation include: (1) a strong suppression of the energy gaps relative to the non-interacting-electrons modeling, and (2) the appearance of a pair of avoided crossings arising between states associated with two-electron occupancies in the left and right wells. The Wigner molecule is a physical entity associated with electron localization within each well and it cannot be captured by the previously employed independent-particle or two-site-Hubbard theoretical modeling of the hybrid qubits. The emergence of strong WMs is investigated in depth through the concerted use of FCI-adapted diagnostic tools like charge and spin densities, as well as conditional probability distributions. Furthermore, the energy spectrum as a function of the strength of the Coulomb repulsion (at constant detuning) is calculated in order to complement the thorough analysis of the factors contributing to WM emergence. We report remarkable agreement with recent experimental measurements. The present FCI methodology for multi-well quantum dots can be straightforwardly extended to treat valeytronic two-band Si/SiGe hybrid qubits, where the central role of the WMs was confirmed recently. Such valeytronic FCI could be also adapted and employed, shortly, in simulations of Si-based two-qubit logical gates, made of two interacting DQD hybrid qubits confining a total of  $N \leq 6$  electrons.

# I. INTRODUCTION

Methodical control of the parameters and performance of qubits is a prerequisite for the succesful implementation of quantum computing. To this effect during the last decade, major experimental endeavors (see, e.g., Refs. [\[1–](#page-13-0) [7\]](#page-13-1)) have been undertaken and substantial progress has been reported. In particular, unprecedented progress has been achieved in the techniques for controlling and manipulating the spin and charge electronic degrees of freedom of two-dimensional (2D) semiconductor hybriddouble-quantum-dot (HDQD) qubits  $[8-15]$  $[8-15]$ , comprising three-electron (3e)  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  $[8-10, 12, 13, 15]$  and five-electron (5e) [\[11,](#page-14-5) [14\]](#page-14-6) varieties.

Nonetheless, several experimental scrutinies in the last two years on state-of-the-art semiconductor double-dot Si/SiGe [\[14\]](#page-14-6) and GaAs [\[15\]](#page-14-1) HDQD qubit devices have provided incontrovertible evidence (see also Refs. [\[16,](#page-14-7) [17\]](#page-14-8)) that a key factor influencing the qubit spectra and performance had been overlooked in the context of earlier qubit investigations. This factor is the manifestation of strong electron-electron (e-e) correlations leading to formation of Wigner molecules (WMs) [\[18](#page-14-9)[–31\]](#page-14-10), which rearranges sharply the electronic spectra of the qubit device with respect to those associated with non-interacting electrons. As their name suggests, the WMs are a fully quantal extension of the concept of a bulk Wigner crystal [\[32\]](#page-15-0) to the realm of finite systems.

From a theoretical perspective, the formation of Wigner molecules cannot be described in the framework of independent-particle (single-particle) modeling [\[8,](#page-14-0) [33,](#page-15-1) [34\]](#page-15-2), which was advanced for 2D quantum dots (QDs) from the very early stages of the field [\[35\]](#page-15-3); nor the more involved *two-site* Hubbard models  $[8, 36-41]$  $[8, 36-41]$  $[8, 36-41]$  $[8, 36-41]$ are adequate in this respect [\[42\]](#page-15-6). As reaffirmed recently for the pilot case of two particles (two electrons [\[14–](#page-14-6) [17\]](#page-14-8) or two holes [\[17\]](#page-14-8)) in a single QD, explored in recent experimental investigations [\[14,](#page-14-6) [15\]](#page-14-1), formation of WMs, which has been extensively demonstrated in earlier investigations [\[18,](#page-14-9) [20,](#page-14-11) [21,](#page-14-12) [23,](#page-14-13) [27–](#page-14-14)[30,](#page-14-15) [43,](#page-15-7) [44\]](#page-15-8), requires the employment of more comprehensive, ab-initio-innature, theoretical approaches, including the symmetrybreaking/symmetry-restoration [\[18,](#page-14-9) [20,](#page-14-11) [23,](#page-14-13) [29\]](#page-14-16) methods and the full configuration-interaction (FCI) method (referred to also as exact diagonalization, [\[21,](#page-14-12) [27–](#page-14-14)[30,](#page-14-15) [43–](#page-15-7) [46\]](#page-15-9)).

In this paper, we demonstrate the central role that strong e-e correlations and WM formation play in shaping the spectra of semiconductor qubits by going beyond the aforementioned recent two-particle CI calculations in a single dot  $[14-17]$  $[14-17]$ , namely, we present FCI calculations for the case of a hybrid  $[8-15, 33]$  $[8-15, 33]$  $[8-15, 33]$  $[8-15, 33]$  three-electron doublequantum-dot GaAs qubit, treated as an integral unit. To establish contact with an actual experimental investigation, we employ HDQD parameters comparable to those in Ref. [\[15\]](#page-14-1), which measured the energy spectrum of the qubit as a function of the detuning at zero magnetic field.

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As we elaborate below, we find a remarkable agreement between our 3e-CI energy spectra and the essential experimental trends that characterize the hybrid qubit. These trends include the large suppression of the energy gaps compared to the simple non-interacting-electron problem and the emergence of the phenomenological 4x4 effective Hamiltonian, which incorporates a pair of avoided crossings associated with double electronic occupancies in the left and right well, and which depends linearly on the detuning between the two wells.

We further present a detailed analysis of the interplay of the spectral features of the HDQD and the formation of a WM, by investigating charge and spin-resolved densities, as well as spin-resolved conditional probability distributions (CPDs), for the 6 or 8 lowest-in-energy states of the 3e-DQD spectra for two different cases, namely as a function of detuning (keeping constant the dielectric constant  $\kappa$ ) and as a function of the dielectric constant (keeping the detuning constant). In this context, particularly revealing for the process of WM formation is the contrast of charge densities (see Fig. [1](#page-4-0) below) between a weakly interacting case (with  $\kappa = 1000$ ) and the strongly interacting case (with  $\kappa = 12.5$ ) of the GaAs HDQD qubit.

Plan of the paper: In Sec. [II,](#page-2-0) we introduce the manybody Hamiltonian of the HDQD device model, comprising three electrons in an asymmetric 2D double-well external confinement, which is modeled by a two-centeroscillator (TCO) potential joined by a smooth neck. The values of the model's parameters, employed in the calculations, are specified in this section; they are chosen to address the experiments on GaAs HDQD in Ref. [\[15\]](#page-14-1). Also included (Sec. [II 1\)](#page-3-0) in this section is a restatement of the Wigner parameter  $R_W$  [\[18,](#page-14-9) [29\]](#page-14-16) pertaining to the propensity for Wigner-molecule formation, as well as estimates of the  $R_W$  corresponding to the parameters used in our calculations.

In Sec. [III,](#page-3-1) the CI-calculated energy spectra as a function of the interdot detuning parameter at specific values of the dielectric constant (controlling the strength of the Coulomb repulsion) are discussed (Sec. [III A\)](#page-3-2) for both the case where the inter-electron interaction is taken to be small (simulating the independent-electron limit) and for the actual value appropriate for GaAs (illustrating the effect of strong WM-formation on the eigenvalue spec-tra). Subsequently (Secs. [III A 1](#page-5-0) and [III A 2\)](#page-6-0), we analyze the charge densities and spin structures corresponding to selected values of the detuning parameter away from the avoided crossings, using both spin-resolved charge densities and spin-resolved CPDs. Special attention is devoted in Sec. [III B](#page-7-0) to the evolution of the spectral characteristics and the mixing of WM wave functions (Sec.  $III B 1)$  when the detuning values fall in the neighbor-hood of the avoided crossings. In Sec. [III C,](#page-8-1) we focus on the energy gap between the ground and 1st excited state, and report remarkable agreement with the measurements of Ref. [\[15\]](#page-14-1). We end Sec. [III](#page-3-1) with an analysis (Sec. [III D\)](#page-9-0) of the CI-calculated spectra for GaAs in the

context of a phenomenological matrix Hamiltonian used as a diagnostic tool in previous works on HDQD qubits.

The effects of inter-electron interaction on the Wignermolecule formation and associated spectral characteristics, are further highlighted and accentuated in Sec. [IV](#page-9-1) through the analysis of the CI-calculated spectra and charge densities as a function of the dielectric constant of the material at a constant detuning value. We summarize our results in Sec. [V.](#page-10-0)

Appendix [A](#page-11-0) describes the numerical approach to determine the eigenenergies and eigenstates of the onebody TCO Hamiltonian introduced below in Eq. [\(3\)](#page-3-3). Because the community of quantum-information and quantum-computer scientists have only recently become alerted [\[14–](#page-14-6)[17\]](#page-14-8) to the potentialities of the CI many-body method and the significance of the concept of the Wigner molecule, for completeness and pedagogical reasons, we include two additional Appendices as follows: Appendix [B](#page-12-0) describes the CI methodology, whereas Appendix [C](#page-13-2) describes the diagnostic tools (beyond-mean-field singleparticle densities and CPDs, and their spin-resolved varieties) needed to analyze the CI many-body wave functions and extract the information regarding WM formation and the intrinsic spin structure of the associated CI wave function.

# <span id="page-2-0"></span>II. MANY-BODY HAMILTONIAN AND PARAMETERS OF THE DOUBLE-WELL DEVICE

Following the recent advances  $\left|11, 13-15\right|$  in the fabrication of hybrid qubits, we investigate in this paper the many-body spectra and wave functions of three electrons in an asymmetric two-dimensional double-well external confinement, inplemented by a two-center-oscillator (TCO) potential as described below.

We consider a many-body Hamiltonian for  $N$  electrons of the form

<span id="page-2-1"></span>
$$
\mathcal{H}_{\text{MB}}(\mathbf{r}_i, \mathbf{r}_j) = \sum_{i=1}^N H_{\text{TCO}}(i) + \sum_{i=1}^N \sum_{j>i}^N V(\mathbf{r}_i, \mathbf{r}_j), \quad (1)
$$

where  $\mathbf{r}_i, \mathbf{r}_j$  denote the vector positions of the i and j electron. This Hamiltonian is the sum of a single-particle part  $H_{\text{TCO}}(i)$ , which implements the double-well confinement, and the two-particle interaction  $V(\mathbf{r}_i, \mathbf{r}_j)$ . A notable property of  $H_{\text{TCO}}$  is the fact that it allows for the formation of a smooth interwell barrier between the individual wells; see the inset of Fig.  $1(b)$  $1(b)$  for an illustration.

Naturally, for the case of electrons, the two-body interaction is given by the Coulomb repulsion

$$
V(\mathbf{r}_i, \mathbf{r}_j) = \frac{e^2}{\kappa |\mathbf{r}_i - \mathbf{r}_j|},\tag{2}
$$

where  $\kappa$  is the dielectric constant of the semiconductor material.

In the two-dimensional TCO employed by us, the single-particle levels associated with the confining potential are determined by the single-particle hamiltonian [\[18,](#page-14-9) [23,](#page-14-13) [44\]](#page-15-8)

<span id="page-3-3"></span>
$$
H_{\rm TCO} = \frac{\mathbf{p}^2}{2m^*} + \frac{1}{2}m^*\omega_y^2 y^2 + \frac{1}{2}m^*\omega_{xk}^2 x_k'^2 + V_{\rm neck}(x) + h_k,\tag{3}
$$

where  $x'_k = x - x_k$  with  $k = 1$  for  $x < 0$  (left) and  $k = 2$  for  $x > 0$  (right), and the  $h_k$ 's control the relative depth of the two wells, with the detuning defined as  $\varepsilon =$  $h_1 - h_2$ , y denotes the coordinate perpendicular to the interdot axis  $(x)$ . The most general shapes described by  $H$  are two semiellipses connected by a smooth neck  $[V_{\text{neck}}(x)].$   $x_1 < 0$  and  $x_2 > 0$  are the centers of these semiellipses,  $d = x_2 - x_1$  is the interdot distance, and  $m^*$ is the effective electron mass.

For the smooth neck, we use

$$
V_{\text{neck}}(x) = \frac{1}{2} m^* \omega_{xk}^2 \Big[ C_k x_k'^3 + \mathcal{D}_k x_k'^4 \Big] \theta(|x| - |x_k|), \quad (4)
$$

where  $\theta(u) = 0$  for  $u > 0$  and  $\theta(u) = 1$  for  $u < 0$ . The four constants  $\mathcal{C}_k$  and  $\mathcal{D}_k$  can be expressed via two parameters, as follows:  $\mathcal{C}_k = \frac{2 - 4\epsilon_k^b}{x_k}$  and  $\mathcal{D}_k = \frac{1 - \epsilon_k^b}{x_k}$  $3\epsilon_k^b)/x_k^2$ , where the barrier-control parameters  $\epsilon_k^b = (V_b (h_k)/V_{0k}$  are related to the height of the targeted interdot barrier  $(V_b,$  measured from the zero point of the energy scale), and  $V_{0k} = m\omega_{x_k}^2 x_k^2/2$ . We note that measured from the bottom of the left  $(k = 1)$  or right  $(k = 2)$  well the interdot barrier is  $V_b - h_k$ .

How we solve for the eigenvalues and eigenstates of  $H_{\text{TCO}}$  is described in Appendix [A.](#page-11-0)

Motivated by the asymmetric double-dot used in the GaAs device described in Ref. [\[15\]](#page-14-1), we choose the parameters entering in the TCO Hamiltonian as follows: The left dot is elliptic with frequencies corresponding to  $\hbar\omega_{x1}$  = 0.413567 meV = 100 h·GHz and  $\hbar\omega_{y1}$  = 1.22 meV = 294.9945 h·GHz (1 h· GHz = 4.13567  $\mu$ eV), whereas the right dot is circular with  $\hbar\omega_{x2} = \hbar\omega_{y2} =$  $1.22 \text{ meV} = 294.9945 \text{ h} \cdot \text{GHz}$ . The left dot is located at  $x_1 = -120$  nm, whereas the right dot is located at  $x_2 = 75$  nm, and the interdot barrier is set to  $V_b = 3.3123$  $meV = 800.91$  h·GHz. The effective electron mass and the dielectric constant for GaAs are  $m^* = 0.067m_e$  and  $\kappa = 12.5$ , respectively.

#### <span id="page-3-0"></span>1. The Wigner parameter

At zero magnetic field and in the case of a single circular harmonic QD, the degree of electron localization and Wigner-molecule pattern formation can be associated with the socalled Wigner parameter [\[18,](#page-14-9) [29\]](#page-14-16)

$$
R_W = Q/(\hbar\omega_0),\tag{5}
$$

where Q is the Coulomb interaction strength and  $\hbar\omega_0$ is the energy quantum of the harmonic potential confinement (being proportional to the one-particle kinetic

Naturally, strong experimental signatures for the formation of Wigner molecules are not expected for values  $R_W \leq 1$ . In the double dot under consideration here, there are two different energy scales,  $\hbar\omega_1$  = 0.413567 meV (associated with the long x dimension of the left QD) and  $\hbar\omega_2 = 1.22$  meV (associated with the right circular QD). As a result, for GaAs (with  $\kappa = 12.5$ ) one gets two different values for the Wigner parameter, namely  $R_{W,1} = 5.31$  and  $R_{W,2} = 3.09$ . These values suggest that a stronger Wigner molecule should form in the left QD compared to the right QD, as indeed was found by the FCI calculation described below; the essentials of the FCI method are presented in Appendix [B.](#page-12-0)

We note that the earlier fabricated GaAs quantum dots had harmonic confinements associated with frequencies  $\hbar\omega_0 \geq 3$  meV  $(R_W < 1.97)$  [\[34,](#page-15-2) [35\]](#page-15-3), which correspond to a range of smaller QD sizes that did not favor the observation of the WMs at zero magnetic fields, as can be concluded from an inspection of the earlier experimental literature [\[47\]](#page-15-10). In this context, the much larger anisotropic GaAs double dot of Ref. [\[15\]](#page-14-1), as well as the findings of Ref. [\[14\]](#page-14-6), where strong WM signatures were observed, heralds the exploration of till now untapped potentialities in the fabrication and control of quantum dot qubits.

## <span id="page-3-1"></span>III. CI SPECTRA AS A FUNCTION OF DETUNING

Before engaging in detailed analyses of the CI numerical results, we comment on a particular notation that will be essential in facilitating this task. Indeed, we will extensively use the three-part notation  $(n_L, n_R; S)$  (with  $n_L + n_R = N$  to denote the left-well electron occupation, the right-well electron occupation, and the total spin, respectively, associated with a 3e CI wave function. In this vein, the two-part notation  $(n_L, n_R)$  will also be occasionally used

#### <span id="page-3-2"></span>A. The big picture

Fig. [1](#page-4-0) compares the CI spectra as a function of detuning (within the same window, 1.40 meV  $\leq \varepsilon \leq 2.1$  meV) for two different values of the dielectric constant, i.e.,  $\kappa = 1000$ , which is closer to the non-interacting limit, and  $\kappa = 12.5$ , which is the actual value for GaAs QDs.

This comparison demonstrates a dramatic modification in the spectra. Indeed, the low-energy spectrum for  $\kappa = 1000$  [including the ground state, see Fig. [1\(](#page-4-0)a)] is dominated by states that have the majority of electrons (two or all three electrons) residing in the deeper right well; such states are denoted as  $(1, 2; S)$  or  $(0, 3; S)$ . According to the socalled branching diagram [\[48,](#page-15-11) [49\]](#page-15-12), for



<span id="page-4-0"></span>FIG. 1. Spectra for the same three-electron double dot for two different values of the dielectric constant. (a)  $\kappa = 1000$  (weak Coulombic repulsion). (b)  $\kappa = 12.5$  (actual value for GaAs, stronger Coulombic repulsion). (c-h) Charge densities for the ground and first five excited states for  $\kappa = 1000$ . (i-n) Charge densities for the ground and first five excited states for  $\kappa = 12.50$ . The arrows indicate the value of the detuning at which the charge densities were calculated, i.e.,  $\varepsilon = 1.50$  meV for (c-h) and  $\varepsilon = 1.405$  for (i-n). The notation  $(n_L, n_R; S)$  denotes the left electron occupation, the right electron occupation, and the total spin, respectively. For all densities, the scales of all three axes are as in (g). CI left and right occupations are highlighted in red.

three electrons the allowed total spin values are  $S = 1/2$ (with a multiplicity of two) and  $S = 3/2$  (with a multiplicity of one). All five lowest-in-energy states in Fig. [1\(](#page-4-0)a) have a total spin  $S = 1/2$ , with the  $S = 3/2$  states appearing at higher energies (at the top of the plotted energy spectrum).

On the contrary, in the corresponding low-energy spec-trum in the GaAs case [Fig. [1\(](#page-4-0)b)], the  $(2, 1; S)$  states with two electrons in the *left* well are prominent, along the  $(1, 2; S)$  states with two electrons in the right well. Furthermore, states with three electrons in a given well, denoted as  $(3,0; S)$  or  $(0,3; S)$ , are absent. The fact that only the six  $(2, 1; S)$  and  $(1, 2; S)$  states comprise the lowest-energy spectrum for the GaAs double dot is an essential feature that is a prerequisite for the implementation of the hybrid qubit which uses [\[8,](#page-14-0) [9,](#page-14-17) [13,](#page-14-4) [15,](#page-14-1) [33\]](#page-15-1) the four  $(2, 1; 1/2)$  and  $(2, 1; 1/2)$  states. As it is discussed below, this feature is the effect of the formation of Wigner molecules as a result of the strengthening of the typical Coulomb energies relative to the energy gaps in the single-particle spectrum of a confining external potential that represents a rather large-size and strongly asymmetric double dot (see the discussion on the Wigner parameter  $R_W$  in Sec. [II 1\)](#page-3-0).

To assist the reader in the exploration of the features present in the spectra of Fig. [1,](#page-4-0) we have successivley numbered the lowest six states at  $\varepsilon = 1.4$  meV, starting from the ground state  $(\#1)$  and moving upwards to the first five excited ones. Apart from the immediate neighbohood of an avoided crossing, in both spectra, these energy curves are straight lines, and naturally we keep the same numbering for all values of the detuning in the window range used in Figs.  $1(a,b)$  $1(a,b)$ .

In Fig.  $1(a)$  $1(a)$ , there are no degeneracies, and this numbering is self-explanatory. The spectrum in Fig.  $1(b)$  $1(b)$  is less transparent, because of quasi-degeneracies between states  $\#2$  and  $\#3$  and  $\#5$  and  $\#6$ , as well as the small energy gap (∼ 3 h·GHz) between state #1 and the quasidegenerate pair ( $\#2,\#3$ ). We stress that the states  $\#1$ and  $#2$  have two electrons in the left well and total spin  $S = 1/2$ , and thus they are denoted as  $(2, 1; 1/2)$ , whereas state  $#3$  has two electrons in the left well, but a total spin of  $S = 3/2$  [denoted as  $(2, 1; 3/2)$ ]. On the other hand, states #4, #5 (with  $S = 1/2$ ), and #6 (with  $S = 3/2$ ) have two electrons in the right well and they are denoted as  $(1, 2; S)$ . A main feature of this six-state spectrum in Fig. [1\(](#page-4-0)b) is that, apart from the neighborhoods of the two avoided crossings (see below Sec. [III B\)](#page-7-0), the energy curves for the states  $\#1$ ,  $\#2$ , and  $\#3$  form one band of parallel lines, whereas the energy curves for the states  $\#4, \#5,$ and #6 form a second band of parallel lines, and the two bands intersect at two avoided crossings. Again the appearance of such three-member bands, grouping together two  $S = 1/2$  states and one  $S = 3/2$  state, is a consequence of the formation of a 3e Wigner molecule (three localized electrons considering both wells), and this is in consonance with the findings of Ref. [\[43\]](#page-15-7) regarding the spectrum of three electrons in single anisotropic quantum dots in variable magnetic fields.

We further stress that the dominant feature in the spectrum of Fig.  $1(b)$  $1(b)$  is the small energy gap between the two  $S = 1/2$  states  $\#1$  and  $\#2$ , which contrasts with the large gap between the other two  $S = 1/2$  states  $\#4$ and #5, a point that will be discussed in detail in Sec. [III C](#page-8-1) below.

# <span id="page-5-0"></span>1. Charge densities away from the avoided crossings

Further insight into the unique trends and properties of the GaAs double dot with the parameters listed in Sec. [II](#page-2-0) is gained through an inspection of the CI-calculated charge densities, plotted in Fig. [1](#page-4-0) for the ground and first five excited states and for both values  $\kappa = 1000$ [see Figs. [1\(](#page-4-0)c-h)] and  $\kappa = 12.5$  [see Figs. 1(i-d)] of the dielectric constant.

To facilitate the identification and illucidation of the main trends, we display, along with the charge densities, the CI-obtained electron occupancies (red lettering) in the left an right wells of the DQD (rounded to the second decimal point). [These CI occupations are rounded further to the closest integer in order to yield the  $n<sub>L</sub>$ 's and  $n_R$ 's  $(n_L + n_R = 3)$  used in the notation  $(n_L, n_R; S)$ to characterize the energy curves in the spectra in Figs.  $1(a,b)$  $1(a,b)$ . Naturally, the charge densities are normalized to the total number of electrons  $N = 3$ .

Inspection of the charge densities on the left (for  $\kappa =$ 1000, that is, for highly weakened inter-electron repulsion) reveals that they conform to those expected from an independent-particle system. Indeed, in Figs.  $1(c,f,g)$  $1(c,f,g)$ , two electrons with opposite spins occupy the lowest nodeless 1s-type single-particle level in the right well. At the same time, the single electron in the left well can occupy succesively the zero-node [Fig.  $1(c)$  $1(c)$ ], one node [Fig.  $1(f)$ ], and two-node  $[Fig. 1(g)]$  $[Fig. 1(g)]$  $[Fig. 1(g)]$  single-particle states in this well. The 5th-excited state is a  $(2,1)$  [Fig. [1\(](#page-4-0)h)] state with two electrons with opposite spins occupying the lowest nodeless single-particle level in the left well, whereas the third electron occupies the nodeless single-particle level of the right well. Finally, the 2nd-excited and 3rd-excited states [Figs.  $1(d,e)$  $1(d,e)$ ] are  $(0,3)$  states with all three electrons residing in the right well. In a circular dot, these two states would be degenerate and fully circular with angular momenta  $+1$  and  $-1$ , but here the degeneracy is lifted because of the influence of the left well and the inter-well neck.

The charge densities on the right (for  $\kappa = 12.5$ , case of GaAs) deviate strongly from those expected from an independent-particle system. Indeed the formation of a strong 2e WM in the left well and of a weaker 2e WM in the right well is clearly seen. For example, contrast the  $(2, 1)$  independent-particle density in Fig.  $1(h)$  $1(h)$  with the  $(2, 1)$  WM density in Figs.  $1(i,j,k)$  $1(i,j,k)$  and the  $(1, 2)$ independent-particle density in Fig.  $1(c)$  $1(c)$  with the  $(1, 2)$ WM density in Figs.  $1(l,m,n)$  $1(l,m,n)$ . We also note the absence of states with higher than double-occupancy in



<span id="page-6-1"></span>FIG. 2. The spin structure of the ground state at  $\kappa = 12.5$ and  $\varepsilon = 1.405$  [see Fig. [1\(](#page-4-0)i) for the corresponding total charge density]. (a) The spin-up density. (b) The spin-down density. The red decimal numbers in (a) and (b) indicate the CI-calculated left and right occupancies (rounded to the second decimal point). (c,d) Examples of two of the associated spin-resolved CPDs. The red dots and arrows indicate the position and spin direction of the fixed point. The black arrows indicate the spin direction associated with the plotted surface. The spin-resolved densities integrate to the number of spin-up and spin-down electrons in (a) and (b), respectively. The scale of the vertical axes in (c) and (d) is arbitrary, but the same in both cases.

any of the DQD wells, unlike the findings for the case of highly quenched inter-electron interaction discussed above; such states may emerge as highy-excited states for GaAs DQDs with the parameters used here (as well as in the experiments [\[15\]](#page-14-1)), and need not to be of concern for future application of such DQDs.

### <span id="page-6-0"></span>2. Spin structure away from the avoided crossings

The charge densities of the states  $\#1, \#2, \text{ and } \#3 \text{ in}$ the three-member band for  $\kappa = 12.5$  [see Figs. [1\(](#page-4-0)i,j,k)] are very similar. However the corresponding spin structures are different, as shown explicitly below. Differences between the spin structures may be investigated with the employment of: (1) spin-resolved densities, and (2) spinresolved conditional probability disctributions. The concept of spin-resolved densities is self-evident. The concept of the spin-resolved CPDs is more complicated, and the full definition is provided in Appendix [C.](#page-13-2) At the intuitive level, the spin-resolved CPD addresses the following question: given the specific (fixed) location  $r_0$  of an electron with a definite spin (up or down), what is the



<span id="page-6-3"></span>FIG. 3. The spin structure of the 1st-excited state at  $\kappa = 12.5$ and  $\varepsilon = 1.405$  [see Fig. [1\(](#page-4-0)j) for the corresponding total charge density]. (a) The spin-up density. (b) The spin-down density. The red decimal numbers in (a) and (b) indicate the CI-calculated left and right occupancies (rounded to the second decimal point). (c,d) Examples of two of the associated spin-resolved CPDs. The red dots and arrows indicate the position and spin direction of the fixed point. The black arrows indicate the spin direction associated with the plotted surface. The spin-resolved densities integrate to the number of spin-up and spin-down electrons in (a) and (b), respectively. The scale of the vertical axes in (c) and (d) is arbitrary, but the same in both cases.

probability distribution at another location r for finding another electron with a definite (up or down) spin?

As an example of the spin-structure analysis that can be achieved with the CI calculations, we analyze below the two cases of the ground state and the 1st-excited state for  $\kappa = 12.5$  (GaAs) and  $\varepsilon = 1.405$  meV.

Fig.  $2(a)$  $2(a)$  and Fig.  $2(b)$  display, respectively, the spinup and spin-down densities for the ground state mentioned above; compare Fig.  $1(i)$  $1(i)$  for the total charge density. From these two spin-resolved densities, it is evident that the spin structure of this ground state conforms to the following familiar expression  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  in the theory of three-electron qubits:

<span id="page-6-2"></span>
$$
(\ket{duu} - \ket{udu})/\sqrt{2},\tag{6}
$$

where  $u$  and  $d$  denote an up and down spin, respectively, with the three spins arranged from left to right in three ordered sites.

Further confirmation for the spin structure in Eq. [\(6\)](#page-6-2) is obtained from the spin-resolved CPDs, two examples of which are displayed in Figs.  $2(c)$  $2(c)$  and  $2(d)$ . Indeed both the spin kets in Eq.  $(6)$  are compatible with a first electron with spin up being fixed at the third site. Then the first spin ket in Eq. [\(6\)](#page-6-2) allows the presence of a spin-up electron in its second site with probability  $1/4$ , whereas the second spin ket allows the presence of a spin-up electron in its first site, again with equal probability 1/4. This is clearly in agreement with the CI CPD plotted in Fig.  $2(c)$  $2(c)$ , which exhibits two humps of similar height at sites No. 1 and No. 2. Likewise, only the second spin ket in Eq.  $(6)$  is compatible with a first electron with spin up being fixed in the first site, and this spin ket allows the presence of a spin-down electron in its second site with probability 1/4. This again is in agreement with the CI CPD plotted in Fig.  $2(d)$  $2(d)$ , which exhibits a single hump at site No. 2.

Fig.  $3(a)$  $3(a)$  and Fig.  $3(b)$  display the spin-up and spindown densities for the associated 1st-excited state; compare Fig.  $1(j)$  $1(j)$  for the total charge density. From these two spin-resolved densities, one can conclude that the spin structure of this 1st-excited state conforms to a second familiar expression  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  $[8, 15, 41, 50]$  in the theory of three-electron qubits, namely

$$
(2|uud\rangle - |duu\rangle - |udu\rangle)/\sqrt{6}.
$$
 (7)

Indeed, from Eq. [\(7\)](#page-7-1), one can derive that the expected spin-up occupancy for the most leftward and middle positions of the three spins is 5/6 in both cases, yielding  $5/3 = 1.666$  for the expected spin-up occupancy in the left dot, in agreement with the CI value of 1.66 highlighted in red in Fig.  $3(a)$  $3(a)$ . Similarly the expected spin-up occupancy for the right dot from Eq.  $(7)$  is  $1/3 = 0.333$ , in agreement with the CI-value of 0.34 highlighted in red in Fig.  $3(a)$  $3(a)$ . Moreover from Eq.  $(7)$ , one can derive that the expected spin-down occupancy for the most leftward and middle positions of the three spins is 1/6 in both cases, yielding  $1/3 = 0.333$  for the expected spin-down occupancy in the left dot, in agreement with the CI value of 0.33 highlighted in red in Fig.  $3(b)$  $3(b)$ . Finally the expected spin-down occupancy for the right dot from Eq.  $(7)$  is  $2/3 = 0.666$ , in agreement with the CI-value of 0.67 highlighted in red in Fig. [3\(](#page-6-3)b).

As aformentioned, further confirmation for the spin structure in Eq. [\(7\)](#page-7-1) can be obtained from the spinresolved CPDs, two examples of which are displayed in Figs.  $3(c)$  $3(c)$  and  $3(d)$ . Indeed only the second and third spin kets in Eq. [\(7\)](#page-7-1) are compatible with a first electron with spin up being fixed at the third site. Then the second spin ket in Eq. [\(7\)](#page-7-1) allows the presence of a spin-up electron in its second site with probability  $1/6$ , whereas the third spin ket allows the presence of a spin-up electron in its first site, again with equal probability 1/6. This is clearly in agreement with the CI CPD plotted in Fig.  $3(c)$  $3(c)$ , which exhibits two humps of similar height at sites No. 1 and No. 2. Likewise, only the first and third spin kets in Eq. [\(7\)](#page-7-1) are compatible with a first electron with spin up being fixed in the first site. Then the first spin ket allows the presence of a spin-down electron in its third site with probability  $2/3$ , whereas the third spin ket allows the presence of a spin-down electron in its second site with probability  $1/6$ . This again is in agreement

with the CI CPD plotted in Fig. [3\(](#page-6-3)d), which exhibits two humps with relative height 1/4 at sites No. 2 and No. 3.

We stress that the two expressions in Eqs. [\(6\)](#page-6-2)-[\(7\)](#page-7-1) for the spin structures of three fermions are not the most general ones. The most general [\[51\]](#page-15-14) expression for a total spin  $S = 1/2$  with a total-spin projection  $S_z = 1/2$  is [\[52\]](#page-15-15):

$$
\sqrt{\frac{2}{3}}\sin\vartheta|uud\rangle + \left(\sqrt{\frac{1}{2}}\cos\vartheta - \sqrt{\frac{1}{6}}\sin\vartheta\right)|udu\rangle -\left(\sqrt{\frac{1}{2}}\cos\vartheta + \sqrt{\frac{1}{6}}\sin\vartheta\right)|duu\rangle,
$$
(8)

where the angle  $\vartheta$  can take any value in the interval  $[\pi/2, 3\pi/2]$ . Eq. [\(6\)](#page-6-2) is recovered for  $\vartheta = \pi$ , whereas its companion orthogonal expression [\(7\)](#page-7-1) is recovered for  $\vartheta = \pi/2$ . Thus it is gratifying to see that the FCI solutions, analyzed with the CPDs, that are associated with the hybrid-qubit device of Ref. [\[15\]](#page-14-1) do not deviate from the spin structures invoked in building the theorical models of three-electron qubits [\[8,](#page-14-0) [41,](#page-15-5) [50\]](#page-15-13).

#### <span id="page-7-0"></span>B. The avoided crossings

<span id="page-7-1"></span>In Fig.  $4(a)$  $4(a)$  and Fig.  $4(b)$ , we display magnifications of the neighborhoods of the left and right CI avoided crossings, respectively, appearing in the spectrum of the GaAs double dot [Fig. [1\(](#page-4-0)b)]. Only the  $S = 1/2$  states are shown, because the  $S = 3/2$  states are not relevant for the workings of the hybrid qubit [\[8,](#page-14-0) [15,](#page-14-1) [41,](#page-15-5) [50\]](#page-15-13).

The left avoided crossing (situated in the neighborhood of 1.49 meV  $\epsilon \leq 1.54$  meV) is formed through the interaction of the three curves  $\#1, \#2, \text{ and } \#4$  [we keep the same numbering of curves here as in Fig.  $1(b)$  $1(b)$ . On the other hand, the curves  $\#1, \#2$ , and  $\#6$  participate in the formation of the right avoided crossing in the neighborhood of 1.885 meV  $\epsilon \leq 1.908$  meV. We note that, according to the FCI calculation, the two avoided crossings are separated by a detuning energy-interval of  $\sim$  400  $\mu$ eV, which agrees with the experimentally determined value for the hybrid qubit device in Ref. [\[15\]](#page-14-1).

The continuous lines in both panels of Fig. [4](#page-8-2) represent the socalled adiabatic paths, which the system follows for slow time variations of the detuning. For fast time variations of the detuning, or with an applied laser pulse, the system can instead follow the diabatic paths indicated explicitly with dashed lines in Fig.  $4(a)$  $4(a)$  and thus jump from one adiabatic line to another; this occurs according to the celebrated Landau-Zener-Stückelberg-Majorana [\[53–](#page-15-16) [55\]](#page-16-0) dynamical interference theory.

We further mention that the position and the asymmetric anatomy of the two avoided crossings play an essential role in the operation of the hybrid qubit. Indeed, the qubit is initialized on line  $\#4$  and in a  $(1, 2; 1/2)$ ground-state configuration at a value of detuning far to the right of the left crossing. Then by decreasing the magnitude of the detuning in an adiabatically evolving



<span id="page-8-2"></span>FIG. 4. Magnification of the neighborhoods of the CI avoided crossings appearing in Fig. [1\(](#page-4-0)b) ( $\kappa = 12.5$ , case of GaAs). Only the  $S = 1/2$  states, relevant to the hybrid qubit, are shown. (a) The left avoided crossing in the neighborhood of 1.49 meV  $\epsilon \leq 1.54$  meV. (b) The right avoided crossing in the neighborhood of 1.885 meV  $\epsilon \leq 1.908$  meV.

manner, the state of the qubit moves along the  $#4$  line and is brought in the neighborhood of the left avoided crossing, where a laser pulse induces a small-gap-enabled diabatic transition to the line  $\#1$  [a  $(2, 1; 1/2)$  line]. Next by increasing the detuning value, the qubit operation cycle proceeds by moving adiabatically backwards along the  $#1$  line and through the right avoided crossing transitioning to the line  $\#6$  [a  $(1, 2; 1/2)$  line], where the readout can be implemented, aided by the large energy gap between the two  $(1, 2; 1/2)$  states  $\#4$  and  $\#6$  [\[9,](#page-14-17) [15\]](#page-14-1).



<span id="page-8-3"></span>FIG. 5. Examples of charge densities at the left avoided cross-ing of the spectrum in Fig. [1\(](#page-4-0)b), namely at  $\varepsilon = 1.5201$  and  $\kappa = 12.5$  (a) The ground state. (b) The 1st-excited state. Both states have a total spin  $S = 1/2$ . The red decimal numbers indicate the left-right electron occupancies according to the CI calculation (rounded to the second decimal point).

#### <span id="page-8-0"></span>1. Charge densities at the avoided crossings: Mixing of WM states

Inside the neighborhood of the avoided crossings, it is expected that the ground state will be a superposition of the two different wave functions  $(2, 1)$  (with two electrons in the left well) and  $(1, 2)$  (with two electrons in the right well). For  $\kappa = 12.5$ , this is confirmed by the CI groundstate charge density [see Fig.  $5(a)$  $5(a)$ ] at the detuning value of  $\varepsilon = 1.5201$  meV [middle point in the neighborhood of the left avoided crossing; see Fig.  $4(a)$  $4(a)$ . Indeed the associated left and right electron occupancies equal both 1.50, suggesting the the CI ground state is a superposition given by  $(|1\rangle + |4\rangle)/\sqrt{2}$ . Likewise, at the same value of  $\varepsilon = 1.5201$  meV, the charge density of the 1st-excited CI state [see Fig.  $5(b)$  $5(b)$ ] exhibits left and right electron occupancies equal to 1.64 and 1.36, respectively, suggesting that this state is a superposition given by  $0.8|1\rangle - 0.6|4\rangle$ .

# <span id="page-8-1"></span>C. The energy gap between the ground and 1st-excited states

To further highlight the notable specifications of the GaAs double dot considered in this paper, we display in Fig. [6](#page-9-2) the CI-calculated energy gap between the ground and the 1st-excited state as a function of the detuning for  $\kappa = 12.5$  (GaAs) [see the spectrum in Fig. [1\(](#page-4-0)b)]. Fig.  $6(a)$  $6(a)$  displays the broader view in the detuning range from 1.4 meV to 2.1 meV covering both avoided crossings. In reference to the spectrum in Fig.  $1(b)$  $1(b)$ , this energy gap involves the following states: (1) The states  $\#1$  and  $\#2$ to the left of the left avoided crossing,  $(2)$  the states  $\#4$ and  $#1$  between the two avoided crossings, and  $(3)$  the states  $#4$  and  $#6$  to the right of the right avoided crossing. Fig.  $6(a)$  $6(a)$  highlights the overarching rise by an order of magnitude of this energy gap, from  $\sim$  3 h⋅GHz to  $\sim$  83 h·GHz, as the spectrum transitions from the  $(2, 1)$  to the (1, 2) configurations with two electrons in the left and right dots, respectively. We note that this behavior is in excellent agreement with the sharp rise of the corre-



<span id="page-9-2"></span>FIG. 6. The CI-calculated energy gap between ground and 1st-excited states as a function of the detuning for  $\kappa = 12.5$  $(GaAs)$  [see the spectrum in Fig. [1\(](#page-4-0)b)]. (a) In the broader range from 1.4 meV to 2.1 meV covering both avoided crossings. (b) In a smaller range [see the dashed-border box in (a)] covering the left avoided crossing.

sponding energy gap within a detuning range of  $\sim$  400  $\mu$ eV proposed in the experimental paper of Ref. [\[15\]](#page-14-1) [see Fig. S5(b) therein].

Moreover, Fig.  $6(b)$  $6(b)$  magnifies the corresponding energy gap in a smaller range [see the dashed-border box in Fig.  $6(a)$  $6(a)$ ] covering only the left avoided crossing. The CI-calculated curve in [6\(](#page-9-2)b) exhibits remarkable overall agreement with the corresponding measured one in Fig.  $1(b)$  of Ref. [\[15\]](#page-14-1) [see also Fig. S5(b) therein].

<span id="page-9-0"></span>In this section, we extract from the CI spectra the phenomenological effective matrix Hamiltonian [\[9,](#page-14-17) [15\]](#page-14-1) that has played a central role in the experimental dynamical control of the hybrid cubit. The general form of this  $4\times4$ matrix Hamiltonian is:

<span id="page-9-3"></span>
$$
H_M = \begin{pmatrix} c_L \tilde{\varepsilon}/2 & 0 & \delta_1 & -\delta_2 \\ 0 & c_L \tilde{\varepsilon}/2 + \Delta E_L & -\delta_3 & \delta_4 \\ \delta_1 & -\delta_3 & c_R \tilde{\varepsilon}/2 & 0 \\ -\delta_2 & \delta_4 & 0 & c_R \tilde{\varepsilon}/2 + \Delta E_R \end{pmatrix},
$$
(9)

where  $\tilde{\varepsilon} = \varepsilon - \varepsilon_0$  denotes a renormalized interdot detuning, and the other elements of the matrix follow the notation used in Ref. [\[9\]](#page-14-17) (see the Theory section therein).

A good fit with the CI spectrum in Figs.  $1(b)$  $1(b)$  and [4](#page-8-2) is achieved by setting  $c_L = 4.4$ ,  $\Delta E_L = 15 \mu \text{eV}$ ,  $c_R = 2.7$ ,  $\Delta E_R = 340 \text{ } \mu\text{eV}, \delta_1 = 0.657 \text{ } \mu\text{eV}, \delta_2 = 0.090 \text{ } \mu\text{eV}, \delta_3 =$ 1.207  $\mu$ eV,  $\delta_4 = 0.075 \mu$ eV, and  $\varepsilon_0 = 1.50 \text{ meV}$ .

The effective matrix Hamiltonian in Eq. [\(9\)](#page-9-3) reflects (within the plotted window) two properties of the FCI spectrum in Fig.  $1(b)$  $1(b)$  that are instrumental (see, e.g., [\[9,](#page-14-17) [56\]](#page-16-1)) for the successful operation of the hybrid qubit, namely, the quasi-linear dependence of  $H_M$  on the detuning  $\varepsilon$  and the quasi-parallel behavior of both the two  $(2, 1)$  states (states  $\#1$  and  $\#2$ ) and the two  $(1, 2)$  states (states  $\#4$  and  $\#6$ ). We note a difference between Refs. [\[9,](#page-14-17) [15\]](#page-14-1) and the CI result for  $H_M$ . Namely, Refs. [9, 15] assume the values  $c_L = 1$  and  $c_R = -1$  associated with  $45^{\circ}$  and  $-45^{\circ}$  slopes of the associated lines, respectively, while the CI result produces different slopes associated with  $c_L = 4.4$  and  $c_R = 2.7$ . We note, however, that the topology of the energy spectrum remains unaltered.

We further note that there are several derivations [\[8,](#page-14-0) [38\]](#page-15-17) of the effective Hamiltonian in Eq. [\(9\)](#page-9-3) starting from approximate many-body Hamiltonians that include the interaction at the level of a two-site (left and right well) Hubbard-type modeling. These derivations involve several additional qualitative approximations and are not applicable in the case of strong  $e - e$  correlations and Wigner-molecule formation (see Ref. [\[42\]](#page-15-6)). Thus the reaffirmation demonstrated above regarding the overall structure of the phenomenological-in-nature effective matrix Hamiltonian [Eq. [\(9\)](#page-9-3)], achieved here through the use of FCI-based ab-initio calculations carried out in the regime of strong correlations and Wigner-molecule formation, is a notable result.

# <span id="page-9-1"></span>IV. CI SPECTRA AS A FUNCTION OF THE DIELECTRIC CONSTANT

Further insights into the effects of the interelectron interaction can be gained by an inspection of the CI spectra as a function of the dielectric constant  $\kappa$ . Fig. [8](#page-11-1) portrays the spectrum of the double dot as a function of the dielectric constant  $\kappa$  at a detuning value of  $\varepsilon = 1.50$  meV. The

-100 0 100 200 300 400 500  $0 -$ 50 100 150 200 250  $\left| \right|$  Effective model ε (μeV) (1,2) (1,2,12) (2) 1/2) (2,11/2) Ene rgy (h GHz) **1 6 6 4 4 2 1 2**  $-40$   $-20$  0 20 35 40 45 50 55 60 **4 4 1 2 1 2** (a)  $\begin{array}{c|c} 35 & / \end{array}$  (b) 375 385 395 405 255 260 265 270 **2 2 1 1 6 6** (c)

65

FIG. 7. The spectrum of the four hybrid-qubit states  $|1\rangle$ ,  $|2\rangle$ ,  $|4\rangle$ , and  $|6\rangle$  (with  $S = 1/2$ ) as a function of the detuning parameter  $\tilde{\epsilon} = \epsilon - \epsilon_0$ , calculated with the effective matrix Hamiltonian in Eq. [\(9\)](#page-9-3);  $\epsilon_0 = 1.51$  meV. (a) The full spectrum. (b) Magnification of the left avoided crossing. (c) Magnification of the right avoided crossing. For the employed values of the 8 parameters  $c<sub>L</sub>$ ,  $\delta E_L$ ,  $c_R$ ,  $\delta E_R$ ,  $\delta_1$ ,  $\delta_2$ ,  $\delta_3$ ,  $\delta_4$ , see the text. Note the remarkable agreement between the 4-state effective spectrum here and the corresponding one of the 4 lowest  $S = 1/2$  states in Figs. [1\(](#page-4-0)b) and [4,](#page-8-2) which was generated from the FCI calculations.

numbering of the lowest 8 states is performed at  $\kappa = 30$ , and this numbering is maintained for the whole  $\kappa$  range plotted. The vertical dashed line at  $\kappa = 12.7$  indicates the neighborhood of the avoided crossing. Further to the left of the avoided crossing, the ground state is state  $#3$ of  $(2, 1; 1/2)$  character; further to the right of the avoided crossing, the ground state is state  $\#1$  of  $(1, 2; 1/2)$  character. In the neighborhood of the avoided crossing, the ground state is a mixed state. In this plot, the groundstate energies were taken at all instances to coincide with the zero of the energy scale. The  $(n_L, n_R; S)$  designations are not plotted in this figure, but they can be traced through Fig. [9,](#page-12-1) which portrays the associated charge densities.

From the charge densities in Fig. [9,](#page-12-1) one sees that at  $\kappa = 30$  the three excited states #3, #6, and #7 display a 2e WM in the left dot, with the WM aligned along the x-axis. With decreasing  $\kappa$  (increasing Coulomb repulsion), the energies of this triad of WM states exhibit a sharp drop in magnitude, and as a result they become the lowest-energy band for  $\kappa < 12.7$ , a fact which agrees with the findings in Sec. [III A.](#page-3-2) In addition the  $\#6$  ( $S = 3/2$ ) and  $\#7$  ( $S = 1/2$ ) curves become quasi-degenerate, and they exhbit a small energy gap ( $\leq 3$  h·GHz) from the ground state  $(\#3 \text{ state})$ , again in agreement with the findings in Sec. [III A;](#page-3-2) see curves numbered  $#1, #2,$  and  $\#3$  in Fig. [1\(](#page-4-0)b).

Of interest is the fact that the ground state at  $\kappa = 30$  $(\#1 \text{ state})$  exhibits a charge density that can be undestood purely with the help of three non-interacting electrons [see Fig.  $9(a)$  $9(a)$ ], namely one spin-up and one spindown electrons occupying the nodeless 1s lowest singleparticle state of the circular right well and one spinup electron occupying the nodeless  $1s_x1s_y$  lowest singleparticle state in the asymmetric left well. Naturally, as  $\kappa$ 

decreases, the intrinsic structure of the associated wave function transitions smoothly to that of a weak 2e WM in the right dot aligned along the y-axis, namely the charge density in Fig.  $9(a)$  $9(a)$  transitions to that portrayed in Fig. [1\(](#page-4-0)l).

Of interest also are the intrinsic structures (at  $\kappa = 30$ ) of the remaining four excited states,  $\#2, \#4, \#5, \text{ and}$  $#8$ ; they are a testament to the variety and complexity of the 3e DQD system. Indeed, from Fig.  $9(b)$  $9(b)$ , one sees that excited state  $#2$  is a non-interacting 3e state similar to state  $#1$ , but with the single spin-up electron in the left well promoted to the one-node  $1p_x1s_y$  single-particle state. On the other hand, the charge densities in Figs. [9\(](#page-12-1)d) and 9(e) demonstrate that both states  $\#4$  and  $\#5$ exhibit a 2e WM in the right well, with the WM aligned along the y-axis. Finally, the charge density in Fig.  $9(h)$  $9(h)$ reveals the formation of a 2e WM in the right well, but with the WM aligned along the  $x$ -axis.

### <span id="page-10-0"></span>V. SUMMARY

We presented extensive FCI numerical results that addressed both the energetics and the intrinsic structure of the many-body wave functions through the calculation of charge and spin-resolved densities, as well as spin-resolved conditional probability distributions (spinresolved two-body correlation functions). Going beyond the two-particle WMs studied with pilot-project CI treatments in a single dot  $[14–17]$  $[14–17]$ , this paper enabled for the first time the microscopic investigation of key features appearing in the low-energy spectrum as a function of detuning of actual experimentally fabricated GaAs threeelectron asymmetric HDQD qubits. These features include the strong suppression of level gaps compared to



<span id="page-11-1"></span>FIG. 8. Spectrum of the double dot as a function of the dielectric constant  $\kappa$  at a detuning value of  $\varepsilon = 1.50$  meV. The numbering of the lowest 8 states is performed at  $\kappa = 30$ , and this numbering is maintained for the whole  $\kappa$  range plotted. The vertical dashed line at  $\kappa = 12.7$  indicates the neighborhood of the avoided crossing. Further to the left of the avoided crossing, the ground state is state  $\#3$  of  $(2, 1; 1/2)$  character; further to the right of the avoided crossing, the ground state is state  $\#1$  of  $(1, 2; 1/2)$  character. In the neighborhood of the avoided crossing, the ground state is a mixed state. In this plot, the ground-state energies were taken at all instances to coincide with the zero of the energy scale. For the  $(n_L, n_R; S)$ designations, see Fig. [9.](#page-12-1)

the non-interacting-electrons case and the appearance of a pair of avoided crossings between triad of levels corresponding to different electron occupancies in the left and right wells. Treating the HDQD as an integral unit, we further showed in depth that these features arise from the emergence of WMs. Away from the avoided crossings, it was found that the WMs can be associated with molecular configurations centered in the individual wells. In the neighborhood of the avoided crossings, the WMs interact and form more complex resonating structures.

Earlier experimental observations had suggested that the qubit's spectral features could be codified using simple phenomenological effective matrix Hamiltonians [see, e.g., Eq. [\(9\)](#page-9-3)]. Our double-dot extensive calculations, encompassing both energetic and structural aspects, enabled tracing of the microscopic origins of such phenomenological treatments. This phenomenology has been identified here to emerge from the complex nature of the many-body problem encountered due to the strong e-e correlations, leading to electron localization and formation of Wigner molecules.

Previous tentative derivations [\[8,](#page-14-0) [38\]](#page-15-17) of matrix Hamil-

tonians [of a similar structure as in Eq.  $(9)$ ], starting from approximate two-site Hubbard-type modeling, involve qualitative approximations and are not applicable in the case of WM formation. Consequently, the present CI-based derivation of the effective matrix Hamiltonian in Eq. [\(9\)](#page-9-3), achieved here via analysis using the results of FCI calculations that account fully for strong-correlation effects within each well and WM formation, is an unexpected auspicious result.

Our multi-dot FCI method can be expanded to incorporate the valley degree of freedom as an isospin in full analogy with the usual spin. Such an expansion will enable the acquisition of numerical results complete with full spin-isospin assignments that will reveal the underlying  $SU(4) \supset SU(2) \times SU(2)$  group-chain organization of the spectra of Si double-quantum-dot qubits. This valleytronic CI [\[62\]](#page-16-2) will be a most effective tool for analysing the spectra of qubits and for providing effective matrix Hamiltonians that differentiate between cases when the first excited state belongs to the same or different valleys, as a result of the competition [\[14,](#page-14-6) [16\]](#page-14-7) between the valley gap and strong  $e - e$  interactions. In this respect, we note the case of a 5e-HDQD Si/SiGe qubit where more complex spectra, requiring an  $n \times n$  matrix with  $n > 4$ , have been recently experimentally discovered [\[63\]](#page-16-3). An application of the valleytronic CI to two-qubit gates appears to be feasible [\[62\]](#page-16-2) in the near future, based on our estimates of the size of the required Hilbert spaces for an ensemble of  $N \leq 6$  electrons confined in two interacting DQDs. Finally, beyond the GaAs-based devices, our method can be directly applied to similar devices built from other one-band materials, like holes in Germanium [\[57,](#page-16-4) [58\]](#page-16-5) or Silicon [\[17\]](#page-14-8) qubits.

# VI. ACKNOWLEDGMENTS

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# <span id="page-11-0"></span>Appendix A: SOLVING THE TWO-CENTER-OSCILLATOR EIGENVALUE PROBLEM

For a given interwell separation  $d$ , the single-particle levels of  $H_{\text{TCO}}$  [Eq. [\(3\)](#page-3-3) ] are obtained by numerical diagonalization in a basis consisting of the eigenstates of the auxiliary hamiltonian:

<span id="page-11-2"></span>
$$
H_0 = \frac{\mathbf{p}^2}{2m^*} + \frac{1}{2}m^*\omega_y^2 y^2 + \frac{1}{2}m^*\omega_{xk}^2 x_k'^2 + h_k .
$$
 (A1)

The eigenvalue problem associated with the auxiliary hamiltonian [Eq.  $(A1)$ ] is separable in the x and y vari-



<span id="page-12-1"></span>FIG. 9. Charge densities for the lowest 8 states of the double quantum dot at  $\kappa = 30$  and  $\varepsilon = 1.50$  meV. The numbering of states is according to Fig. [8.](#page-11-1) The red decimal numbers indicate the left-right electron occupancies according to the CI calculations (rounded to the second decimal point). For a detailed description, see the text.

ables, i.e., the wave functions are written as

<span id="page-12-2"></span>
$$
\varphi_i(x, y) = X_\mu(x) Y_n(y), \tag{A2}
$$

with  $i \equiv {\mu, n}, i = 1, 2, ..., K$ . K specifies the size of the single-particle basis.

The  $Y_n(y)$  are the eigenfunctions of a one-dimensional oscillator, and the  $X_\mu(x \leq 0)$  or  $X_\mu(x > 0)$  can be expressed through the parabolic cylinder functions  $U[\gamma_k, (-1)^k \xi_k]$ , where  $\xi_k = x'_k \sqrt{2m^* \omega_{xk}/\hbar}, \gamma_k = (-E_x +$  $(h_k)/(\hbar\omega_{xk}),$  and  $E_x = (\mu + 0.5)\hbar\omega_{x1} + h_1$  denotes the xeigenvalues. The matching conditions at  $x = 0$  for the left and right domains yield the  $x$ -eigenvalues and the eigenfunctions  $X_u(x)$ . The *n* indices are integer. The number of  $\mu$  indices is finite; they are in general real numbers.

#### <span id="page-12-0"></span>Appendix B: THE CI METHOD AS ADAPTED TO THE DOUBLE-DOT CASE

As aforementioned, we use the method of configuration interaction for determining the solution of the manybody problem specified by the Hamiltonian [\(1\)](#page-2-1).

In the CI method, one writes the many-body wave function  $\Phi_N^{\text{CI}}(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N)$  as a linear superposition of Slater determinants  $\Psi^N(\mathbf{r}_1, \mathbf{r}_2, \dots, \mathbf{r}_N)$  that span the many-body Hilbert space and are constructed out of the single-particle spin-orbitals

$$
\chi_j(x, y) = \varphi_j(x, y)\alpha, \quad \text{if} \quad 1 \le j \le K,\tag{B1}
$$

and

$$
\chi_j(x, y) = \varphi_{j-K}(x, y)\beta, \quad \text{if} \quad K < j \le 2K,\tag{B2}
$$

where  $\alpha(\beta)$  denote up (down) spins, and the spatial orbitals  $\varphi_i(x, y)$  are defined in Eq. [\(A2\)](#page-12-2). Namely

<span id="page-12-4"></span>
$$
\Phi_{N,q}^{\rm CI}(\mathbf{r}_1,\ldots,\mathbf{r}_N)=\sum_{I} C_I^q \Psi_I^N(\mathbf{r}_1,\ldots,\mathbf{r}_N),\qquad(B3)
$$

where

<span id="page-12-3"></span>
$$
\Psi_I^N = \frac{1}{\sqrt{N!}} \begin{vmatrix} \chi_{j_1}(\mathbf{r}_1) & \cdots & \chi_{j_N}(\mathbf{r}_1) \\ \vdots & \ddots & \vdots \\ \chi_{j_1}(\mathbf{r}_N) & \cdots & \chi_{j_N}(\mathbf{r}_N) \end{vmatrix}, \quad \text{(B4)}
$$

and the master index  $I$  counts  $[59]$  the number of arrangements  $\{j_1, j_2, \ldots, j_N\}$  under the restriction that  $1 \leq j_1 < j_2 < \ldots < j_N \leq 2K$ . Of course,  $q = 1, 2, \ldots$ counts the excitation spectrum, with  $q = 1$  corresponding to the ground state.

The many-body Schrödinger equation

$$
\mathcal{H}\Phi_{N,q}^{\text{CI}} = E_{N,q}^{\text{CI}} \Phi_{N,q}^{\text{CI}} \tag{B5}
$$

transforms into a matrix diagonalizatiom problem, which yields the coefficients  $C_I^q$  and the eigenenergies  $E_{N,q}^{\text{CI}}$ . Because the resulting matrix is sparse, we implement its numerical diagonalization employing the well known ARPACK solver [\[60\]](#page-16-7). Convergence of the many-body solutions is guaranteed by using a large enough value for the dimension  $K$  of the single-particle basis; see Appendix [A.](#page-11-0) The attribute "full" is usually used for such well converged CI solutions, which naturally contain all possible  $np - nh$  basis Slater determinants.

The matrix elements  $\langle \Psi_N^I | \mathcal{H} | \Psi_N^J \rangle$  between the basis determinants [see Eq.  $(B4)$ ] are calculated using the Slater

rules [\[44,](#page-15-8) [61\]](#page-16-8). Naturally, an important ingredient in this respect are the matrix elements of the two-body interaction,

$$
\int_{-\infty}^{\infty} \int_{-\infty}^{\infty} d\mathbf{r}_1 d\mathbf{r}_2 \varphi_i^*(\mathbf{r}_1) \varphi_j^*(\mathbf{r}_2) V(\mathbf{r}_1, \mathbf{r}_2) \varphi_k(\mathbf{r}_1) \varphi_l(\mathbf{r}_2),
$$
\n(B6)

in the basis formed out of the single-particle spatial orbitals  $\varphi_i(\mathbf{r}), i = 1, 2, ..., K$  [Eq. [\(A2\)](#page-12-2)]. In our approach, these matrix elements are determined numerically and stored separately.

The Slater determinants  $\Psi_I^N$  [see Eq. [\(B4\)](#page-12-3)] conserve the third projection  $S_z$ , but not the square  $\hat{S}^2$  of the total spin. However, because  $\hat{S}^2$  commutes with the manybody Hamiltonian, the CI solutions are automatically eigenstates of  $\hat{S}^2$  with eigenvalues  $S(S+1)$ . After diagonalization, these eigenvalues are determined by applying  $\hat{\mathbf{S}}^2$  onto  $\Phi_{N,q}^{\text{CI}}$  and using the relation [\[48\]](#page-15-11)

$$
\hat{\mathbf{S}}^2 \Psi_I^N = \left[ (N_\alpha - N_\beta)^2 / 4 + N/2 + \sum_{i < j} \varpi_{ij} \right] \Psi_I^N, \quad \text{(B7)}
$$

where the operator  $\varpi_{ij}$  interchanges the spins of fermions i and j provided that these spins are different;  $N_{\alpha}$  and  $N_{\beta}$ denote the number of spin-up and spin-down fermions, respectively.

# <span id="page-13-2"></span>Appendix C: SINGLE-PARTICLE DENSITIES AND CONDITIONAL PROBABILITY DISTRIBUTIONS FROM CI WAVE FUNCTIONS

The single-particle density (charge density) is the expectation value of the one-body operator

$$
\rho(\mathbf{r}) = \langle \Phi_N^{\text{CI}} | \sum_{i=1}^N \delta(\mathbf{r} - \mathbf{r}_i) | \Phi_N^{\text{CI}} \rangle, \tag{C1}
$$

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where, as previously,  $\Phi_N^{\text{CI}}$  denotes the many-body (multideterminantal) CI wave function (henceforth, we will drop the q subscript). For the spin-resolved densities, the expression above is modified as follows:

$$
\rho_{\sigma}(\mathbf{r}) = \langle \Phi_N^{\rm CI} | \sum_{i=1}^N \delta(\mathbf{r} - \mathbf{r}_i) \delta_{\sigma \sigma_i} | \Phi_N^{\rm CI} \rangle, \tag{C2}
$$

where  $\sigma$  denotes either an up or a down spin.

Naturally several distinct spin structures can correspond to the same charge density. The spin structure associated with a specific CI wave function can be determined uniquely with the help of the spin-resolved densities in conjunction with the many-body spin-resolved CPDs.

The spin-resolved CPDs (referred to also as spinresolved two-point anisotropic correlation functions) yield the conditional probability distribution of finding another fermion with up (or down) spin  $\sigma$  at a position r, assuming that a given fermion with up (or down) spin  $\sigma_0$  is fixed at  $r_0$ . In detail, a spin-resolved CPD is defined as

$$
P_{\sigma\sigma_0}(\mathbf{r}, \mathbf{r}_0) = \langle \Phi_N^{\text{CI}} | \sum_{i \neq j} \delta(\mathbf{r} - \mathbf{r}_i) \delta(\mathbf{r}_0 - \mathbf{r}_j) \delta_{\sigma\sigma_i} \delta_{\sigma_0\sigma_j} | \Phi_N^{\text{CI}} \rangle.
$$
\n(C3)

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tween CI densities (as well as conditional probabilities; see Appendix [C](#page-13-2) for definitions) and spin eigenfunctions (see Ref.  $[48]$  and Eqs.  $(6)$  and  $(7)$ ). Such a mapping was discussed in detail in Ref. [\[44\]](#page-15-8) for four electrons in a double quantum dot and for three ultracold fermionic atoms in a double optical trap in C. Yannouleas, B.B. Brandt, and U. Landman, Ultracold few fermionic atoms in needle-shaped double wells: spin chains and resonating spin clusters from microscopic Hamiltonians emulated via antiferromagnetic Heisenberg and  $t-J$  models, New J. Phys. 18, 073018 (2016), DOI: [https://doi.org/](https://doi.org/10.1088/1367-2630/18/7/073018) [10.1088/1367-2630/18/7/073018](https://doi.org/10.1088/1367-2630/18/7/073018). This strong-WM  $\leftrightarrow$ spin-eigenfunctions mapping implies that the strong-WM physics can be interpreted qualitatively using the limiting case (for large  $U/t$ ) of the Hubbard model known as the Heisenberg model. At a minimum, however, the number of sites in such a Heisenberg modeling is  $N$  (the number of localized fermions), and even larger in the case of a resonance between the left and right potential wells; for details, see again the two references mentioned above in this footnote. Elaborating further on such a Heisenbergmodel interpretation in the context of a double-dot qubit is beyond the scope of the present paper.

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